



# **Description:**

High-power industrial transistor

NPN silicon power transistor designed for applications in industrial and commercial equipment including high fidelity audio amplifiers, series and shunt regulators and power switches

### Features:

- The 2N3442 is a Silicon power base transistor for high power audio, series pass power supplies, disk-head positioners and other linear application. These devices can also be used in power switching circuits such as converters or inverters
- Higher safe operating area than 2N3442 at V<sub>CF</sub> >40V
- Low saturation voltages
- · High power dissipation capability

# **Maximum Ratings**

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	140		
Collector-Base Voltage	V <sub>CB</sub>	160	V DC	
Emitter-Base Voltage	V <sub>EB</sub>	7		
Collector Current-Continuous -Peak	I <sub>C</sub>	10 15	A DC	
Base Current-Continuous -Peak	I <sub>B</sub>	7 -	A DC	
Total Power Dissipation at T <sub>C</sub> = 25°C Derate above 25°C (Note 2)	P <sub>D</sub>	117 0.67	W W/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +200	°C	

# **Thermal Characteristics**

Characteristic	Symbol	Max.	Unit
Thermal Resistance Junction to Case	R <sub>ejc</sub>	1.17	°C/W

Max. ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

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- 1. Indicates JEDEC registered data.
- 2. This data guaranteed in addition to JEDEC registered data.

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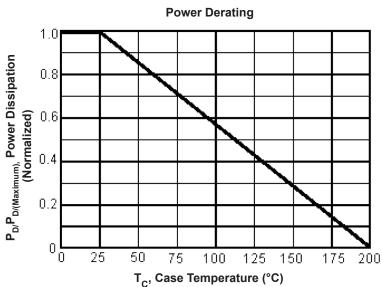
# Electrical Characteristics (TC = 25°C unless otherwise noted)

Characteristic	Symbol	Min.	Max.	Unit
Off Characteristics				
Collector-Emitter Sustaining Voltage (I <sub>C</sub> = 200mA DC, I <sub>B</sub> = 0)	V <sub>EO (sus)</sub>	140	-	V DC
Collector Cut off Current (V <sub>CE</sub> = 140V DC, I <sub>B</sub> = 0 )	I <sub>CEO</sub>	-	200	mA DC
Collector Cut off Current ( $V_{CE}$ = 140 V DC, $V_{BE (off)}$ = 1.5 V DC) ( $V_{CE}$ = 140 V DC, $V_{BE (off)}$ = 1.5 V DC, $T_{C}$ = 150°C)	I <sub>CEX</sub>	-	5 30	
Emitter Cut off Current (V <sub>EB</sub> = 7V DC I <sub>C</sub> = 0 )	I <sub>EBO</sub>	-	5	
On Characteristic (Note 3)				
DC Current Gain ( $I_C = 3A$ DC, $V_{CE} = 4V$ DC) ( $I_C = 10A$ DC, $V_{CE} = 4V$ DC)	h <sub>FE</sub>	2 7.5	70 -	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10A DC, I <sub>B</sub> = 2A DC)	V <sub>CE (sat)</sub>	-	5	V DC
Base-Emitter On Voltage ( $I_C = 10A DC, V_{CE} = 4V DC$ )	V <sub>BE (on)</sub>	-	5.7	
Dynamic Characteristics				
Current-Gain - Bandwidth Product (Note 4) $(I_C = 2A DC, VCE = 4V DC, f_{test} = 40kHz)$	f <sub>T</sub>	80	-	kHz
Small-Signal Current Gain $(I_C = 2A DC, V_{CE} = 4V DC, f = 1kHz)$	h <sub>fe</sub>	12	72	-

# Note:

(3) Pulse Test : Pulse Width = 300µs, Duty Cycle ≤2%

(4)  $f_T = | hfe | \cdot ftest$ 

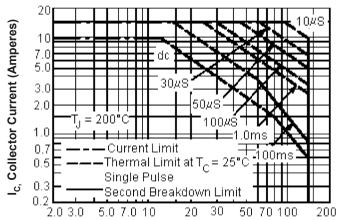


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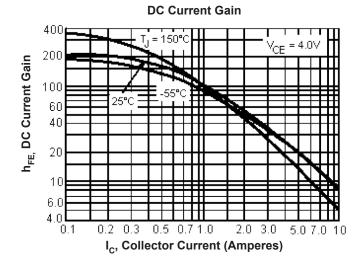
# **Active-Region Safe Operating Area Information**



V<sub>CE.</sub> Collector Emitter Voltage (Volts)

There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $\rm I_C^- V_{CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data is based on  $T_{J\,(PK)}$  = 200°C;  $T_{C}$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



# Olector Emitter Voltage 1.0 1.2 -I<sub>C</sub> = 1.0A - 2.0A - 4.0A - 8.0A 0.8 0.8 0.6 0.4 0.4 0.7 1 = 25°C

50

I<sub>R</sub> Base Current (mA)

5.0

**Collector-Saturation Region** 

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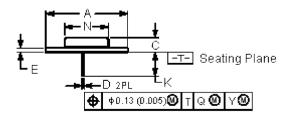
100 200

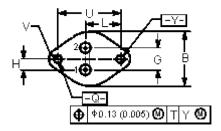
500 1.0k 2.0k



# **Dimensions:**

(TO-3)





### Pin Configuration:

Pin 1. Base

2. Emitter Collector (Case)

Dimensions	Min.	Max.	
А	1.55 (39.37) Reference		
В	-	1.05 (26.67)	
С	0.25 (6.35)	0.335 (8.51)	
D	0.038 (0.97)	0.043 (1.09)	
E	0.055 (1.4)	0.07 (1.77)	
G	0.43 (10.92) BSC		
Н	0.215 (5.46) BSC		
К	0.44 (11.18)	0.48 (12.19)	
L	0.665 (16.89) BSC		
N	-	0.83 (21.08)	
Q	0.151 (3.84)	0.165 (4.19)	
U	1.187 (30.15) BSC		
V	0.131 (3.33)	0.188 (4.77)	

Dimensions: Inches (Millimetres)

# **Part Number Table**

Description	Part Number
Transistor, NPN, TO-3	2N3442

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